High-order $H$ arm onic Generation and D ynam ic Localization in a driven two-level system, a non-perturbative solution using the $F$ loquet-G reen form alism

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#### Abstract

W e apply the $F$ loquet-G reen operator form alism to the case of a harm on ically-driven tw o-level system. W e derive exact expressions for the quasi-energies and the com ponents of the F loquet eigenstates w ith the use of continued fractions. W e study the avoided crossings structure of the quasi-energies as a function of the strength of the driving eld and give an interpretation in term $s$  operator. U sing th is operator we study D ynam ic Localization and H igh-order H arm on ic G eneration in the non-perturbative regim e.


## I. INTRODUCTION

The driven two-level system is a particularly im portant model in physics, since it has proved to be very usefiul in describing $m$ any aspects of the interaction of $m$ atter $w$ ith an electrom agnetic eld. In the eld of atom ic physics, this system was traditionally studied using the R otating $W$ ave A pproxim ation (RW A), in which the counter-rotating term of the harm onic driving is neglected. This approxim ation is valid only for am plitudes of the driving eld that are $s m$ all com pared to the energy di erence betw een the atom ic states $m$ ost a ected by the driving eld. This was typical for experim ents until the 1960 's. P resently, technical im provem ents in laser technology allow experim enters to produce very strong electrom agnetic elds (laser pulses) which can produce interesting non-linear e ects in their interaction $w$ ith $m$ atter.

The excitation of a spin $1 / 2$ atom or electron in a magnetic eld interacting with a m icrow ave eld is another exam ple where the strength of the driving eld ( RF radiation) can not be assum ed to be sm all.

A lso, due to the progress in lithographic techniques and tunable lasers in the terahertz dom ain, it has becom e possible to construct sem iconductor quantum well stnuctures driven by a strong electrom agnetic eld. In these system $s$, several interesting results have been obtained, including, coherent suppression of tunneling [also called D ynam ic Localization (D L ) ${ }^{\underline{2}, 2}$, collapse of $m$ ini-bands in super-lattiges ${ }^{3}$, absolute negative conductance ${ }^{4,5}$, photonassisted tunneling ${ }^{6}$ and AC stark e ect ${ }^{7}$.
$T$ he driven two-level system has also been used to describe an atom $m$ oving through a Fabry-P erot cavity. 8 In this system, the strong coupling regim $e$ is already accessible both in the $m$ icrow ave and in the visible regim e.

In all of the system smentioned before, where strong elds are involved, the "counter rotating" term in the tim edependent part of the H am iltonian does contribute signi cantly. T herefore, di erent theoretical approaches beyond RW A are required. O ne such method was nst introduced by Autler and Tow nes9. U sing Floquet's theorem and continued fractions, they derived a generalsolution in order to investigate the e ect of a radio frequency eld on the l-type $m$ icrow ave absorption line of the doublet $J=2!1$ of the $m$ olecules of gaseous OCS.

Later, Shirley ${ }^{10}$ em ployed $F$ loquet theory to reduce the solution of a periodic tim e-dependent $H$ am iltonian to the problem of diagonalization of a tim e-independent $m$ atrix. This $m$ atrix $w$ as then used to calculate eigenvalues and transition probabilities for a driven tw o-level system and also to derive higher order (beyond linear RW A ) analytic approxim ations valid in the case of weak driving. Later approaches to this problem, usually w ithin the context of a spin system in a m agnetic and a R F eld, have involved the use of continued fractions ${ }^{11,12,13}$, although the role played by $F$ loquet theory in those approaches (and in particular the role of the quasienergy) is not clear.

A di erent kind of analytical expression for the quasienergy of the system, which does not involve continued fractions w as reported by Zhac ${ }^{14}$. It $m$ akes use of group theoretical argum ents for its derivation and involves the evaluation of com plicated in nite sum s. A part from its intrinsic theoretical value, this solution does not provide a practicalw ay to study this system.

T here have been a variety of approaches used to obtain approxim ate analytic expressions. M ost of them have been
 the frequency of the driving, $!_{0}$ is the energy di erence betw een the two levels of the unperturbed H am iltonian and $v$ is the strength of the driving. O ne of the most interesting features of a system described by these perturbative solutions is that at som e speci c values of the driving eld strength (zeros of the zeroth-orderBesselfunction) D ynam ic Localization ( $\mathrm{D} L$ ) occurs, which in the context of quantum wells m eans that despite a nonzero tunneling probability betw een the wells, a system initially prepared in one of the wells will rem ain in that well inde nitely. A m anifestation of D L [also called C oherent Destruction of Tunneling (CDT)]was rst found in a tight binding potential with an applied AC electric eld ${ }^{20} \mathrm{D} \mathrm{L}$ in quantum wells was rst studied by G ro m ann el al ${ }^{2}$

In a paper by Ivanov ${ }^{21}$ in which $H$ igh-order $H$ arm onic $G$ eneration ( $\mathrm{H} H \mathrm{G}$ ) by diatom ic m olecular ions is considered, and then $m$ ore recently in works by Santana et $\mathrm{al}^{22}$ and also Delgado and G om ez Llorente ${ }^{23}$, analytical expressions in term $s$ of $B$ essel fiunctions were found, valid in the (perturbative) regim e where $D L$ occurs. This regim e can be characterized by the condition $!0=$ ! 0 for any v , or $!_{0}=$ ! $\quad \mathrm{v} \overline{\mathrm{v}=\mathrm{h}!} \quad 1 . \mathrm{Wew}$ ill say that whenever any of these tw o conditions is satis ed, the system is in the D ynam ic Localization Regim e ( $D L R$ ). W hen that regim e is reached, our results converge to the known B essel-finction expressions.

In this w ork we present a fully developed $F$ loquet-G reen form alism for tim e periodic system S , which we then use to derive an exact solution for the two level system with harm onic driving. This exact solution is expressed in term $s$ of continued fractions, suitable to the study of the regim ew here netther the RW A nor any other perturbative approach works. O ur aim is to present a whole picture of this system, of its eigenvalues and eigenstates in the di erent regions of its param eter space and to obtain from the general solution a better understanding of the tw $\mathrm{o} m$ ain features of th is system, nam ely, D ynam ic Localization (D L) and High-Order H arm onic G eneration (H H G ).

In section II we derive the $F$ loquet-G reen operator form alism and establish a connection betw een the poles of this operator and the com ponents of the $F$ loquet eigenstates.

In section III we apply this form alism to the speci c case of the two-state system with harm onic driving. By $m$ aking use of continued fractions, we obtain an expression for the quasi-energies. W e study the structure of avoidedcrossings in the quasi-energies and interpret them in term sofm ulti-photon processes. W e also derive here the $F$ loquet eigenstates (FES) of the system and study their dependence on the am plitude of the driving eld for di erent values of the tw o-levelenergy di erence. The tim e-evolution operator is constructed using the FES.

In section $\mathbb{I V}$, using the abovem entioned operator, we study D ynam ic Localization (D L) , and in section V we study H igh-order H arm onic G eneration ( H H G).

In Section VI we sum $m$ arize our ndings and give som e conchding rem arks.

## II. FLOQUET-GREEN OPERATOR FOR HARMONICDRIVING

$T$ he pioneering work of Shirley ${ }^{10}$ and Sam be ${ }^{24}$ laid down the theoretical foundations for a com plete treatm ent of tim e-periodic potentials, based on the sam e $m$ athem atical tools already developed for tim e-independent potentials. Of great im portance am ong these tools is the G reen's function, whose de nition and application for tim e-periodic system $s$ has not been clear until recently. A $F$ loquet-G reen function $m$ ethod for the solution of radiative electron scattering in a strong laser eld was introduced by Faisal2 ${ }^{25}$. In this work we present a fully developed picture of the $F$ loquet-G reen's operator form alism for general tim e-harm on ic $H$ am iltonians that $w$ as introduced by the author in a previous work ${ }^{26}$, and apply it to the case of a two-state system with harm onic driving.

W e start by considering a H am iltonian of the general form :

$$
\begin{equation*}
\mathrm{H}(\mathrm{t})=\mathrm{H}_{0}+2 \mathrm{~V} \cos (!\mathrm{t}) ; \tag{1}
\end{equation*}
$$

were $H_{0}$ and $V$ are $H$ erm itian operators in the $H$ ibert space ( $H$ ) of the system. Because of the periodicity of the $H$ am iltonian, according to $F$ loquet's theorem, the solutions to Schrodinger's equation ih $\frac{\varrho}{@ t} j(t) i=H(x ; t) j(t) i$ are of the form

$$
\begin{equation*}
j^{e}(t) i=e^{\text {iet=h }} j^{e}(t) \dot{i} ; \tag{2}
\end{equation*}
$$

where $j^{e}(t) i=j^{e}\left(t+\frac{2}{!}\right) i$.
Inserting this into Schrodinger's equation one arrives at the eigenvalue equation

$$
\begin{equation*}
H^{F}(t) j^{e}(t) i=e j^{e}(t) i ; \tag{3}
\end{equation*}
$$

where $H^{F}(t)$ is de ned as

$$
\begin{equation*}
H^{F}(t) \quad H \quad(t) \quad i h \frac{@}{@ t}: \tag{4}
\end{equation*}
$$

A s pointed out by Sam be ${ }^{24}$, since Eq.(3) is an eigenvalue equation, it can be solved using the standard techniques developed for tim e-independent H am iltonians, provided we extend the H ibert space to include the space of tim eperiodic functions. In this extended space, the tim e param eter can be treated as another degree of freedom of the system. A sim ilar concept is used in classicalm echanics, and gives rise to the concept of a "half" degree of freedom when dealing with tim e dependent H am iltonians.

A suitable basis for this extended $H$ ilbert space $(R)$ is $f j i \quad j i ;:: g$, where $f j i ;: g$ is a basis for the $H$ ilbert space $H$ of the system, and we de ne htji $\overline{\bar{N}} e^{\text {in! } t, ~ w i t h ~} n$ integer. C learly fini;:g spans the vector space (T of periodic functions, and therefore, $\mathrm{R}=\mathrm{H} \quad \mathrm{T}$. In this basis, Eq . (3) becom es a m atrix eigenvalue equation of in nite dim ension $w$ ith an in nite num ber of eigenvalues. It is not di cult to proof that if $e_{i}$ is an eigenvalue, $w$ ith corresponding eigenvector $j^{e_{i}}(t) i$, then $e_{i}+m$ is also an eigenvalue (allquantities are assum ed to be in units of $h$ !), $w$ ith corresponding eigenvector $j^{e_{i}+m}(t) i=e^{i m!} t_{j}^{e_{i}}(t) i$. A ccordingly, the eigenstate corresponding to eigenvalue $e_{i}+m$ has the sam e structure than the eigenstate corresponding to $e_{i}$, except that it is displaced by $m$ on the energy axis. Because of th is, to nd all the eigenvectors and eigenvalues of the $F$ loquet $H$ am iltonian one needs only to consider $\frac{1}{2} \quad \mathrm{e}<\frac{1}{2}$. W e w ill use the letter " to refer to the F loquet eigenvalues restricted to this interval and call them "quasi-energies". C learly, any $F$ loquet eigenvahe $e_{i}$ can be written as $e_{i}=\|_{i}+p$ for some $\frac{1}{2} \quad \eta_{i}<\frac{1}{2}$ and some integer $p$. It can be show $n$ that, in general, there are $N$ distinct quasi-energies (except for accidental degeneracies) if the H ibert space H is N dim ensional.
$T$ his periodic structure in the eigenvalues does not $m$ ean that the "replica" eigenstates have no relevance; they are also valid solutions of E q. (3) and are essential for com pleteness in the extended H ibert space R 27 . They also allow us to understand some features of the quasi-energies of the system in term s of avoided crossings betw een "replica" eigenstates.

T he F loquet-G reen operator for the $F$ loquet $H$ am iltonian in $E q$. (3), is de ned by the equation ${ }^{26}$,

$$
\begin{equation*}
\left[1 E \quad H^{F}\left(t^{0}\right)\right] G\left(E ; t^{0} ; t^{\prime \prime}\right)=1 \quad\left(t^{0} \quad t^{0}\right) ; \tag{5}
\end{equation*}
$$

$w h e r e(t)$ is the -periodic delta function $\left(=\frac{2}{!}\right)$.
In term s of the com plete (in nite) set $\mathrm{fj}^{\mathrm{e}_{i}}$ ( t ) ig of eigenfunctions of the F loquet H am iltonian ( Eq q 4 ), the solution for Eq.(5) is

$$
\begin{equation*}
G\left(E ; t^{0} ; t^{\infty}\right)=\underbrace{X}_{i} \frac{j^{e_{i}}\left(t^{0}\right) i h{ }^{e_{i}}\left(t^{\infty}\right) j}{E} e^{j}: \tag{6}
\end{equation*}
$$

From the previous discussion about the eigenvalues and eigenfunctions of the $F$ loquet $H$ am iltonian, we can w rite the $F$ loquet-G reen operator entirely in term s of the eigenfunctions corresponding to values $e_{i}$ betw een $\frac{1}{2}$ and $\frac{1}{2}$. We will denote these eigenvalues as " . U sing this, the F loquet-G reen operator can be w rilten as
where $=1 ;:: \mathbb{N}$ for $H$ being $N$-dim ensional, and $p_{R} R^{1} ;:: ; 1$ 1
o perating on both sides of this equation with $\frac{1}{2} 0_{0} e^{e^{i m!}!t^{0}} e$ in! $t^{\infty 0} d t^{\infty} d t^{0}$ we obtain
where

$$
G_{m ; n}(E)=\frac{1}{2} \int_{0}^{Z} e^{\mathrm{Z} m!t^{0}} e^{\text {in }!t^{\infty}} G\left(E ; t^{0} ; t^{\infty}\right) d t^{\infty} d t^{0} ;
$$

and

$$
\begin{equation*}
j_{m}^{\prime \prime} i=\frac{1}{Z}_{0}^{Z} e^{i m!t^{0}} j^{"}\left(t^{0}\right) i d t^{0}: \tag{9}
\end{equation*}
$$

Form $=n=0$,

$$
\begin{equation*}
G_{0 ; 0}(E)={ }_{; p}^{X} \frac{1}{E \quad " \quad p_{p}^{\prime}} \text { ih }_{p}^{"} j: \tag{10}
\end{equation*}
$$

This last equation show s us the relationship betw een the residue of the operator $G_{\Phi 0}(\mathbb{E})$ at the pole " $+p$ and

conclude that, corresponding to each pole at $E="+p$ of the $F$ loquet-G reen operator $G_{0 ; 0}(E)$ there is an oscillating term of the form $e^{\text {ip! } t}$ in the F loquet eigenstate speci ed by the quasi-energy " .
${ }_{1} \mathrm{~L}_{\mathrm{R}}$ us go back to the task of nding an explicit solution to the F loquet-G reen operator in Eq. 5). Applying $\underline{1}_{0}{ }_{0} e^{i m!} t^{0} e$ in! t"dt"dt on both sides of this equation, and using Eq. (4) together $w$ ith the de nitions above we get

$$
\begin{equation*}
\left[1(E+m) \quad H_{0}\right] G_{m ; n} \quad V\left(G_{n}+1 ; n+G_{m} \quad 1 ; n\right)=1 m ; n \tag{11}
\end{equation*}
$$

$T$ he explicit solution of th is equation, in term sofm atrix continued fractions follow $s$ from ${ }^{26}$. The resulting expression for the operator $G_{0 ; 0}(E)$ is

$$
\mathrm{G}_{0 ; 0}(\mathrm{E})=\left(\begin{array}{llll}
1 \mathrm{E} & \mathrm{H}_{0} & \mathrm{~V}_{\mathrm{e}} & (\mathrm{E}) \tag{12}
\end{array}\right)^{1} ;
$$

where

$$
\mathrm{V}_{\mathrm{e}}(\mathbb{E})=\mathrm{V}_{\mathrm{e}}^{+}(\mathbb{E})+\mathrm{V}_{\mathrm{e}} \text { (E); }
$$

w ith


W e now specialize this result for the case of a tw o state system driven by a classical single frequency potential.

## III. HARM ON ICALLY DRIVEN TW O-LEVEL SYSTEM

In this section we apply the form alism previously presented to the case of a driven two-level system of the form

$$
\begin{equation*}
\mathrm{H}=\frac{\mathfrak{f}_{0}}{2} \mathrm{z}+2 \mathrm{vcos}(!\mathrm{t}) \mathrm{x} \text {; } \tag{14}
\end{equation*}
$$

where $H, t_{0}$ and $v$ are given in units of $h$. In the context ofan electron interacting $w$ ith an electric eld, the am plitude 2 v corresponds to the (static) dipole m om ent of the electron tim es the applied electric eld, i.e. $2 \mathrm{v}=\mathrm{E}_{0}=\mathrm{h}$ !, (the factor of tw o has been introduced for convenience) and the classical electric eld is of the form $E(t)=E_{0} \cos (!t)$. In a double quantum -dot realization of this $H$ am iltonian, the non-driven part, $\frac{\dot{1}_{0}}{2} z$, describes the tunneling betw een the states localized on each dot, fjli; Rig. This tunneling gives rise to a splitting of $h!0=!_{0} h!$ between the energy levels $\frac{h!0}{2} ;+\frac{h!0}{2}$, whose corresponding eigenstates we denote by fjai; joig, and where pi $=\frac{1}{2}$ ( $\left.17 i+2 i\right)$,
 describes tw o bound states of the atom ic (or m olecular) potential, or, in the context of ionizing system s it could also be thought of as describing a bound state and the continuum ${ }^{28,29}$. An electron $m$ oving in a FabryP erot cavity ${ }^{\frac{8}{8} \text { or a }}$ $1 / 2$ spin system $w$ ith an applied $m$ agnetic and $m$ icrow ave eld ${ }^{11,12,13}$, are also exam ples of system $s$ where this $m$ odel has been used.

C ontinued fractionsm ethods have been used before to study this system, specially in the context ofspin $1 / 2$ system $s$ in a m agnetic and RF eld, starting w ith the sem inalw ork of A utler and Tow nes ${ }^{9}$. A lso, a previous treatm ent of th is problem where the tim e dependent $G$ reen's function and continued fractions were used, although w ithout reference to the $F$ loquet form alism can be found in the work by $G u s h$ and $G u s h{ }^{30}$. T here have been several perturbative approaches to this problem, as it was m entioned before. H ere, we will focus on the properties of the exact solution, and in particular we w ill study its dependence on the strength of the driving eld and the connection with HHG and DL.

To nd the exact solution to this H am iltonian we need to evaluate Eq . [12,13), for the case $\mathrm{V}=\mathrm{V} \mathrm{x}$ and $\mathrm{H}_{0}=\frac{!}{2} \mathrm{z}$. It can be checked easily that, given the o -diagonal form of $V$ and the diagonal form of $H_{0}$, the $m$ atrioes $V_{e}$ ( $E$ ) are diagonal. Its diagonal com ponents $w$ ill be denoted respectively by $f_{\mathrm{a}}(E) ; \mathrm{v}_{\mathrm{b}}(\mathbb{E}) \mathrm{g}$. The dynam ic e ective-potential $V_{\mathrm{e}}(\mathrm{E})$ is therefore also diagonal and of the form

$$
\mathrm{V}_{\mathrm{e}}(\mathbb{E})=\begin{gather*}
\mathrm{v}_{\mathrm{a}}^{+}(E)+\mathrm{v}_{\mathrm{a}}(E)  \tag{15}\\
0
\end{gathered} \begin{gathered}
0 \\
\mathrm{v}_{\mathrm{b}}^{+}(E)+\mathrm{v}_{\mathrm{b}}(E)
\end{gather*}:
$$

The $v_{a=b}$ functions are given by the follow ing coupled recursive relations
$R$ eplacing $v_{a}$ into $v_{b}$ (and vice versa) we obtain the de-coupled recursive relations

$$
\begin{align*}
& \mathrm{V}_{\mathrm{b}}(\mathrm{E})=\frac{\mathrm{v}^{2}}{\mathrm{E} \quad 1+\frac{\iota_{0}}{2}} \frac{\mathrm{v}^{2}}{\mathrm{E}} \quad 2 \frac{\dagger_{0}}{2} \quad \mathrm{~J}_{\mathrm{b}}^{ \pm}(\mathrm{E} \quad 2) \quad: ~: ~ \tag{17}
\end{align*}
$$

From Eq.(12), the solution for $\mathrm{G}_{0} ; 0(\mathrm{E})$ is also a diagonalm atrix of the form

$$
\mathrm{G}_{0 ; 0}(\mathbb{E})=\begin{array}{rr}
\mathrm{g}^{\mathrm{a}}(\mathbb{E}) & 0  \tag{18}\\
0 \mathrm{~g}^{\mathrm{b}}(\mathbb{E})
\end{array} ;
$$

w ith

$$
\begin{aligned}
& g^{a}(E)=\frac{1}{E+\frac{t_{0}}{2} \quad \text { 売 (E) } \quad V_{a}(E)} ;
\end{aligned}
$$

It can easily be seen from Eq. (17) that this system possesses the symmetry $v_{a}(E)=V(E)$, which from Eq. (19) gives us $g_{a}(E)=g(E)$. Thismeans that to nd the two quasi-energies of the system one only has to look for a pole in either $g_{a}(\mathbb{E})$ or $g_{b}(\mathbb{E})$ in the range $0: 5 \mathrm{E} \quad 0: 5$; the other pole is sym $m$ etrically located on the opposite side of the (quasi) energy axis.

## A. Poles of $G_{0 ; 0}(E)$ and the quasi-energies of the system

A s discussed before, the quasi-energies of the system can be obtained from the poles in $g_{a}(E)$ and $g_{b}(E)$. We showed that it is su cient to study the poles in only one of these functions since for any pole in $g_{a}(\mathbb{E})$ at $\mathrm{E}=\mathrm{E}$ there is a corresponding pole in $g_{b}(E)$ at $E=E . T h i s i m p l i e s ~ t h e ~ e x i s t e n c e ~ o f ~ t w o ~ q u a s i-e n e r g i e s ~ i n ~ t h e ~ s y s t e m, ~$ "; ". The quasi-energy " can be obtained from the solution to $\Phi(E)^{1}=0$ in the interval $0: 5<E<0: 5$. From Eqs. (17) , (19), the poles of $g_{b}(E)$ satisfy the equation,

where $=\mathrm{E} \frac{\dagger_{0}}{2}$. The quasi-energy is obtained as " $=\left(\frac{\hbar_{0}}{2}+\right) \mathrm{mod} 1$.
In $F$ ig. 1 we show one of the quasi-energies of the system, for di erent values of $t_{0}$. These functions are plotted as a function of the driving strength $v . W$ e have included the resonant case $t_{0}=1$ and several values in the high frequency regim e where $t_{0}<1$. In the lim it when $t_{0} \ll \max \left(1 ; \bar{v}^{p}\right)$, the function " $(\mathrm{v}) \frac{t_{0}}{2} J_{0}(4 \mathrm{v})$. This result was rst obtained by Shirley ${ }^{10}$. It is precisely in this regim ewhere it was show $n^{22,23}$ that $D L$ appears as a dom inant feature. A s $!_{0}$ decreases we observe a very quick convergence to the approxim ate result " (v) $\frac{t_{0}}{2} J_{0}(4 \mathrm{v})$. A lready for $t_{0}=0.25$, the di erence betw een the exact result for " ( $v$ ) and the approxim ation cannot be observed at the scale of the graph. For $\downarrow_{0}=0: 1$ we plotted both " (v) and $"(v)$ to $m$ ake the location of the zeros of $\overline{\mathrm{f}}(4 \mathrm{v}) \mathrm{m}$ ore visible.

A s we can also see in Fig 2, increasing $\downarrow_{0} 0$ alw ays displaces the zeros of " (v) tow ards sm aller values. This behavior $w$ as also observed by $V$ illas $B$ Oas et $l^{31}$ in the case of a double quantum well with an intense AC electric eld and an applied $m$ agnetic eld. $N$ otice also that, as it is easy to derive analytically, the only case when the initial slope of the quasi-energy is not zero is for the resonant case ${ }^{32}$

In $F$ ig. 2 we show the quasi-energy as a function of the driving strength $v$, for low frequencies, where $t_{0} 1$. The resonant case is included for com parison. A lso, the dotted line show s the functions $0: 05 \mathrm{~J}(4 \mathrm{~V})$ in order to indicate the location of the zeros of this B essel function. A s one increases $t_{0}$, the am plitude and sharpness of the oscillations around " $=0$ increases, the location of the zeros shifts to the left, and the parabola that describes (except in the resonant case) the in itialbehavior of the curve opens up. For $t_{0}>2$ one can get from Eq. (20) that the in itialbehavior of the quasi-energy is parabolic and has the form

$$
\begin{equation*}
\text { (v) } \frac{2 t_{0}}{t_{0}^{2}} v^{2} \tag{21}
\end{equation*}
$$

This rem ains a good approxim ation for allvalues ofv until (v) $\frac{t_{0} 1}{4}$, and provided (v) does not reach the edges of the B rillouin zone $(-0.5,0.5)$ before that. If it does so, then, the quasi-energy experiences an avoided crossing, whose sharpness is proportional to $!_{0}$ and decreases with the value of $v$ at which the anti-crossing occurs.

## B . A voided crossings

In $F$ ig. 3 we can see that the structure of the quasi-energy is determ ined by a regular sequence of avoided crossings which get broader as the strength of the driving eld $v$ is increased (resonant case show $n$ in the gure).

Let us consider the rst avoided crossings, the ones along the line marked " 3 ph . res" in F ig. 3. To zero order in $v$, the eigenvalues and eigenvectors of the $F$ loquet $H$ am iltonian are the state vectors jijni; biji, for any integer $n$. In this basis, the tim e-dependent potential can be written as $V=v_{x}\left(a+a^{y}\right)$. W hen the e ect of one photon processes (in the RW A) is included, one obtains that the new set of eigenstates is fin; ig, for any integer $n$, and $w h e r e ~ i n ; ~ i=p \frac{1}{2}$ (jinin bin $1 i$ ). It's corresponding eigenvalues are $\underset{\mu}{e}=\frac{1}{2}+n \quad V$. This one photon process is in a sense an avoided crossing, w ith a w idth that goes to zero as $v!0.0$ ne can see that, near $v \quad 1$, the eigenvalues corresponding to the eigenstates in; i and in 2; i w ould cross if only st order processes where allow ed. To second order this degeneracy is not lifted since hn 2; $\quad \mathrm{ff}^{2} \mathrm{j}$; $i=0$. Only when third order processes are included, this degeneracy is lifted, since it is easy to check that hn 2; fjin if 0 . Third order processes are therefore involved in the avoided crossings near $v 1$.

For the resonant case, after the rst avoided crossing (v 1), for example betw een the states $j 1$; $i$ and $j 1$; $i$, and because of considerable overlap betw een the 3 photon resonance and the 5 photon resonance, this states do not com pletely exchange their identities, as it w ould be the case in a w ell isolated avoided crossing. A n "identity exchange" betw een $F$ loquet states can clearly be observed for values of $t_{0}$ and $v$ for $w$ hidh there is a sharp avoided crossing (i.e. $t_{0}=3: 0$ in $F$ ig.5). In Fig.3, for the resonant case we can see that even though the structure of the eigenstates after the rst avoided crossing is not necessarily of the form jii, the points where the quasi-energies of these " rst-order" FES cross, com e close to the actual location of the avoided crossings. This is an indication that those states are dom inant in the structure of the eigenstates, a fact that can be checked by com paring the actual structure of the FES in Fig. 6, at som e am plitude v, w ith the corresponding " rst order" FES eigenvalues that intersect at the closest avoided crossing in Fig. 3. For v 5 the peak com ponents in the FES are only one unit of energy further out that the expected value from the sim ple picture in Fig3. It is an interesting feature of this system the fact that the FES obtained for sm all driving am plitudes constitute the "bare bones" structure of the FES and to a good extent they determ ine the avoided crossings structure of the quasi-energies (at least for a larger-than-expected range of driving eld am plitudes).
This avoided crossings structure, to a certain approxim ation, can be thought of as mostly due to odd-photon processes betw een FES. Even $m$ ore, we $w i l l$ argue that at least for a range of $v$ ( $0<v<4$ for the resonant case), the $m$ ain contribution to the avoided crossings is a three photon process for the rst avoided crossing, 5 photon for the second avoided crossing, and so on (in the resonant case). For any value of $t_{0}$ we nd that the num ber of photons involved in the rst resonance depends on the in itialdistance betw een the tw o unperturbed levels ( $\ell_{0}$ ). If for exam ple $t_{0}=3$ the rst avoided crossing $w$ ill be the 5 photon resonance ( $F$ ig. 5 ); for $t_{0}=5$ it $w$ ill be the 7 photon resonance, etc. In generalwe can write that, for $t_{0} \quad 1$ the order of the rst resonance is $2 \operatorname{Int}\left(\frac{1}{2}\right)+3$. The avoided crossings picture holds for any $\downarrow_{0}$ provided $v$ is not too big; an estim ate is $v<4 t_{0}^{2}$. A bove this, the overlap betw een di erent photon processes is too big for our sim ple picture to apply.

In Fig.3. it can be seen that the states that intervene at each avoided crossing are of the form $2 \mathrm{kn}+1$; $i$ and
$2 \mathrm{n}+1 \quad 2 \mathrm{~m} ;+\mathrm{i}$, form $=1 ; 2 ; 3:::$. It is easy to check that

$$
\mathrm{h} 2 \mathrm{n}+1 ; \quad \mathrm{Jj}^{\mathrm{q}} 2 \mathrm{n}+1 \quad 2 \mathrm{~m} ;+i \neq 0 ; \quad \text { only for } \mathrm{q}=2 \mathrm{~m} \quad 1 ; 2 \mathrm{~m}+1 ;:::
$$

$T$ his is a good indication that these avoided crossings can be intenpreted as multi-photon resonances that involve odd num bers of photons. From Fig. 3, we see that at the avoided crossing A, from the interacting states jl; i and $j 1 ;+i$, there should be a three photon exchange between jaiji and pij $2 i$ and a 1 photon exchange between jaij $1 i$ and fojoi. From the exact result for the com ponents of one of the FES shown in $F$ ig. 6 we see that the dom inant com ponent before the crossing is jaiji and therefore, at $v=1$ (which is near the crossing), the tw o dom inant com ponents should be jaijli and bij 2i; this corresponds to a three photon process. N ear the avoided crossing B in $F$ ig.3, where v 2, we can see from $F$ ig. 5 that the dom inant com ponents are j; 3i and b; 2i which corresponds to a 5 photon exchange. For values of $t_{0}$ and $v$ for which the avoided crossings are shanper one gets an even clearer picture of those avoided crossing as resulting from the exchange of a speci c odd num ber of photons betw een $F$ loquet states.

It is interesting to see how this description of avoided crossings and photon processes is re ected by the structure of the continued fractions in Eq. (20) and how the di erent term $s$ in it contribute to the features of the quasi-energy as a function of the driving am plitude. From exam ination of Eq . (20) it is not di cult to see that for sm all $v$, each term of the form + gives a solution near $=$. To nd accurately the solution of for a particular value of $v$ one does not need to (nor can) include an in nite num ber of term $s$ in the C F.An im portant question is therefore, how $m$ any term $s$ to include and why? To study this, we rst propose a way to truncate Eq. (20) so that we obtain, in each case, a sym $m$ etrical set of solutions. For illustration we will continue focusing on the particular case of resonance $\left(!_{0}=1\right)$, as it is straight forw ard to apply the sam e ideas show $n$ here for other values of $t_{0}$.

Eq.(20) can be put in the form

$$
\begin{equation*}
\mathrm{F}^{+}(E) \mathrm{F} \quad(E)=\mathrm{v}^{2} ; \tag{22}
\end{equation*}
$$

w ith


To understand the e ect of the di erent term $s$ in the $C$. we will truncate the functions $F$ at di erent levels and plot the solutions for. $\mathrm{F}_{\mathrm{n}}$ refers to the truncated version of F where $\mathrm{v}^{2}$ appears n tim es ${ }^{33}$, i.e.

$$
\mathrm{F}_{0}^{+}=; \mathrm{F}_{1}^{+}=\frac{\mathrm{v}^{2}}{+1+t_{0}} ; \quad \mathrm{F}_{2}^{+}=\frac{\mathrm{v}^{2}}{+1+t_{0} \frac{\mathrm{v}^{2}}{+2}} ;:::: ;
$$

and likew ise for $\mathrm{F}_{\mathrm{n}}$.
In the di erent panels in $F$ ig. 4 we plot the solutions for $(v)$ as obtained from the equation $F_{n}^{+} F_{n}=v^{2}$ for $\mathrm{n}=0 ; 1 ; 2 ; 3$ [panels a) through d$)$ ], and only for the resonant case $!_{0}=1 . \mathrm{We}$ also plot w ith a dashed line and for com parison, the exact result for (only the tw o sm allest roots are shown). A lso, in front of each plot there is an insert $w$ ith a diagram $w$ ith lines and arrow $s$. The lines represent each term that has been included in the continued fractions $F_{n}^{+}$and $F_{n}$. A swem entioned before, each term of the form + contributes w ith an eigenvalue curve that originates at $=$. There are two kinds ofterm softhat form in the C E.'s ofEq20): $2 n$ and $+\frac{1}{6} \quad(2 m+1)$. $T$ he rst ones contribute, at $v=0$, $w$ ith a solution at $=2 n$ and therefore a pole at $E=E_{b} \quad 2 n$. The second kind gives a solution for $=\quad \% \quad(2 \mathrm{~m}+1)$ which contributes $w$ ith a pole at $E=\mathrm{E}_{\mathrm{b}} \quad \dagger_{0} \quad(2 \mathrm{~m}+1)=\mathrm{E}_{\mathrm{a}} \quad(2 \mathrm{~m}+1)$. To the lines on the left we associate the states j; $2 \mathrm{n}+1 \mathrm{i} . \mathrm{W}$ ew ill label this lines as a $+2 \mathrm{n}+1$, for som e n ; the lines on the right we associate $w$ ith the particle- eld states $\frac{1}{} \mathrm{p} ; 2 \mathrm{ni}$ and label them as $\mathrm{b}+2 \mathrm{n}$. A sim ilar picture would result from studying the poles of $g_{a}(E)$.
$W$ hen two such term $s$ in the CF are included, then we see, in the corresponding panel in $F$ ig. 4 , a pair of solutions, which at $\mathrm{v}=0$ converge to $=2 \mathrm{n}$ and split for $\mathrm{v}>0$. W e know, from previous discussions, that the upper one should correspond to the FES, $2 n+1 ;+i=\dot{j} ; 2 n+1 i+j ; 2 n i$, and the lower one to $2 n+1 ; i=j ; 2 n+1 i \quad j ; 2 n i$. $T$ he arrow s at the end of the lines show the direction in which the corresponding eigenvalue would $m$ ove $w h e n ~ v i s$ increased. The repulsion betw een the eigenstates $2 n+1$; $i$ is due to the exchange of one photon betw een $j a i$ and
bi. This is the $m$ ain process at work in panels a) and b). In panel c) two new processes enter the picture: A s the levels $m$ ove apart due to the one photon resonance, another resonance ( $A$ ) can now occur when the levels $j 3$; $i$ and j1; im ostly due to the transfer of three photons betw een j; $3 i$ and $j$; $0 i$. This process appears for the rst tim e for $\mathrm{F}_{2}$ when the term $\dot{j} ; 3 i$ is included in the CF. A replica of this three photon resonance occurs also betw een levels j; iand j 1; + i.

W hen $j$; $3 i$ and $\ddagger$; $2 i$ is included, the second process that becom es available is the ve photon resonance betw een levels $j 3$; $i$ and $j 1 ;+i$ (after th is level have interacted $w i$ th $j$; $+i$ and $j$; $i$ respectively). This resonance becom es $m$ ore clearly de ned in paneld) where $m$ ore levels are included. Even though, as com pared to c), no new resonances appear in d), the inclusion of levels ja; $3 i$ and $p ; 4 i$ contributes to shanpen the resonances already visible in c) and in particular the 5 photon resonance $B$. $T$ his show $s$ that, as $m$ entioned before, there are severalodd-photon processes that contribute to a particular avoided crossing. T here is how ever, an odd num ber of photons that seem s to contribute the $m$ ost and w ithout which, if the corresponding levels are not included, the corresponding avoided crossing does not seem to occur. That speci c num ber of photons is shown on the top of Fig .3 . For v $>4$ this pictures begins to falter, and the avoided crossings begin to depend $m$ ore on a higher num ber of photons than what w ould be predicted from Fig.3. For $v=5$ for exam ple, a better description of the crossing would be for a 15 photon resonant process, not the expected 13. For even higher values of $t_{0}$ this picture holds on a bigger range of the driving eld am plitude, nam ely, for $v<4 t_{0}^{2}$. A smentioned before, one can see that in $F$ ig 5 , for $t_{0}=3$, the rst avoided crossing is clearly a 5 photon resonance.

A s an em pirical rule, which agrees w ith the above observations, we found that to obtain an accurate result for the quasi-energy up to a value $v$ of the driving potential one needs to use the function $F^{n}$ ( $E$ ), with $n>\operatorname{Int}(2 v)$.

## C. C om ponents of the $F$ loquet $E$ igen States

In the previous subsection we show ed how to obtain the diagonal part of the $F$ loquet-G reen operator and discussed its pole structure and their avoided crossings. In this part we study the $F$ loquet eigenstates and the generalbehavior of them as the amplitude of the driving eld changes. In Appendix A we show that the FES of this system can be w ritten in the form

$$
j \quad "(t) i=k(t) \dot{a} i+z(t) \operatorname{bi} i
$$

and

$$
\begin{equation*}
j^{\prime \prime}(t) i=Z(t) \dot{a} i+K(t) \underset{b i}{ } \tag{24}
\end{equation*}
$$

w ith

$$
\begin{align*}
& x^{1} \\
& K(t)=N\left[\quad e^{2 \text { in!t }} K_{2 n}(\quad ")\right] \text {; } \\
& \mathrm{n}=1  \tag{25}\\
& \left.\left.Z(t)=N \sum_{n=1}^{X^{+}} e^{i(2 n} 1\right)!t_{Z_{2 n}}\left(l^{\prime}\right)\right]:
\end{align*}
$$

$N$ is a norm alization constant and $f(t) \xrightarrow{\jmath}+\Downarrow(t) \xrightarrow{\jmath}=1$. In appendix $A$ we also show the explicit form of the com ponents $K_{2 n}, Z_{2 n+1}$, in Eq. (61). It can there be seen that all com ponents $K_{2 n}$ and $Z_{2 n}$ are real, and therefore $K(0)$ and $Z(0)$ are also real num bers.

In $F$ ig. 6 we show the com ponents of one of the $F$ loquet eigenstates of the system, $j$ " ( t )i, for the resonant case, and for eight di erent values of the driving eld am plitude, In the upper gure of each panelwe show the quantities $\mathrm{Z}_{\mathrm{n}}, \mathrm{K}_{\mathrm{n}}$ ( w ith n odd for $\mathrm{Z}_{\mathrm{n}}$ and n even for $\mathrm{K}_{\mathrm{n}}$ ), and in the lower panels we show the quantities $\ln \mathrm{Z}_{\mathrm{n}} j \ln \mathrm{~K}_{\mathrm{n}} j$.

A noticeable qualitative di erence betw een the behavior of $Z_{2 n} \quad$ and $K_{2 n}$ is the fact that for stronger values of v , the form er becom es m ore antisym m etric while the last one becom es m ore sym m etrical around $\mathrm{n}=0$. Wewill com $m$ ent shortly about the consequence that this has for the dynam ic localization of the system. The fact that the eigenstates of the system have com ponents that are harm on ics of the driving eld frequency !, translates, as we w ill study in the next section, into a (coherent) em ission spectrum of the system which contains also many frequencies that are $m$ ultiples of the frequency of the driving eld. T he possibility of exciting a system at a particular frequency $w$ ith a strong eld, and producing radiation that includes $m$ any ham onics of the driving frequency (in som e cases even hundreds of them) is called H igh H arm onic G eneration ( H HG ) and has been studied in m any experim ents ${ }^{34}$ D riven tw o-level system s have been studied in the past to understand the general features of H HG such as the
existence of a plateau in the spectrum follow ed by a sharp cut-o where the am plitudes of the ham onics decrease rapidly $16,21,28,35,36,37,38$

As one can see directly from $F$ ig. 6 (resonant case), in $m$ ost of the cases show $n$, the $F$ loquet eigenstates show a particular structure w th two clearly distinguishable regions. The rst region which, in a non-rigorous way we call the "chaotic" one, can be described as corresponding to the $F$ loquet com ponents with in $j<N_{e}=2 v \quad 1$ (for $\mathrm{v} \quad 1$ in the resonant case). The amplitude of these F loquet com ponents depends strongly on n and on v , and there are frequent sign changes. This gives rise to the "plateau" region typical in HHG. The second region, or the "regular" one corresponds to the com ponents $w$ ith $\eta j>N_{e}$, and it is characterized by having am plitudes that decay exponentially with $n$. A lso, notice that the com ponents $K_{n}$ and $Z_{n}$ do not change sign in that region, $w$ ith $K_{2 n}>0$, and $\operatorname{sg}\left(Z_{2 n} \quad 1\right)=s g\left(n_{p}\right)$ in the " regular" region ( $\left.\operatorname{sg}(x) \quad x=j \bar{j}\right)$. For other values of to, a plateau region was alw ays found whenever $v>P \frac{1}{!_{0}}$ (for $!_{0} \quad 1$, in agreem ent $w$ ith a sim ilar expression obtained by $K$ aplar 28 in the lim it $t_{0} \gg 1$. For $t_{0}<1$, the plateau form $s$ for any $v>1$.

The expression $N_{e}=2 \mathrm{v} \quad 1$ can be derived in a sim ple way. First, we look at the conditions to obtain, for $\mathrm{n}>0$ a perfectly at, triple plateau in the com ponents of the FES. This m eans that we will assume $K_{n+2}=Z_{n+1}=K_{n}$ ( $w$ hich gives three consecutive com ponents $w$ th the sam eam plitude), for som e $n$ even. $T$ his condition can be achieved if, from Eq. (61), $\mathrm{v}_{\mathrm{a}}^{+}("+\mathrm{n})=\mathrm{v}_{\mathrm{b}}^{+}("+\mathrm{n}+1)=\mathrm{v}$. From Eq. (16) we get the condition,

$$
\mathrm{n}=2 \mathrm{v} \quad 1+\frac{\grave{\Lambda}_{0}}{2} \quad ":
$$

If instead, we had chosen the triple plateau to be of the form $Z_{n+2}=K_{n+1}=Z_{n}$ (for $n$ odd), then, the equation for n would be

$$
\mathrm{n}=2 \mathrm{v} \quad 1 \quad \frac{t_{0}}{2} \quad \mathrm{n}:
$$

If we now apply the sam e reasoning for a triple cusp to occur in the negative energy com ponents, beginning at the com ponent $n$, we get the conditions (for $n$ odd and even)

$$
\begin{aligned}
& \mathrm{n}=2 \mathrm{v} \quad 1+\frac{t_{0}}{2}+" ; \\
& \mathrm{n}=2 \mathrm{v} \quad 1 \quad \frac{\grave{\omega}_{0}}{2}+":
\end{aligned}
$$

$C$ learly, since in generalthis 4 equations can not be (nor we care for them to be) satis ed sim ultaneously, we look for a condition that will produce a sim ple (possibly) double cusp, both at $N_{e}$ and $N_{e}$. This would describe the location of the tw o broad peaks that are, in all cases, at the lim it betw een the "chaotic" and the "regular" region. For obtaining th is sym $m$ etric at cusp condition we pick the equation that is right in the $m$ iddle of the set of 4 equations given above. This equation is clearly

$$
\begin{equation*}
\mathrm{N}_{\mathrm{e}}=2 \mathrm{v} \quad 1 ; \tag{26}
\end{equation*}
$$

w th the nice property that the " and the $t_{0}$ dependencedrops out. $T$ his is a result that should work well whenever there is a well de ned "plateau" region, that is, for $v \quad p \frac{l_{0}}{!_{0}}$ when ! $!_{0} 1$, or $v \quad 1$ when $b<1$. As can be seen in Fig.6, for $!_{0}=1$ and $v \quad 1$, this equation seem $s$ to describe well the location of the peaks in the spectrum of an eigenstate that separate the plateau from the exponential decay region. For other values of $t_{0}$ it gives also good agreem ent w th the data.

To investigate further the structure of the FES of the system, we use Eq. (24), and evaluate at $t=0$,

$$
\begin{align*}
& \text { j " }(0) i=\cos j \dot{j} i+\sin \quad \text { joi; } \\
& j "(0) i=\sin \dot{a} i+\cos \text { bi; } \tag{27}
\end{align*}
$$

and where, using $K(0)^{2}+Z(0)^{2}=1$, we have de ned the angle so that $K(0)=\cos$, and $Z(0)=\sin$.
W e now concentrate on the study of the quantities cos (v); sin (v); (v), which, as we will see in the next sections, play an im portant part in the evolution of the system, and correspondingly in the D ynam ical Localization and H arm onic $G$ eneration of the system. In what follow swew ill study them for three di erent values of the param eter $\iota_{0}:$ D riving frequency above resonance, for $!_{0}=0: 5$; resonant case for $\iota_{0}=1$ and driving frequency below resonance, for $t_{0}=2$.

In $F$ igs. 7,8,9, we show the results for $t_{0}=0: 5, t_{0}=1: 0$ and $t_{0}=2: 0$ respectively. The upper panels show the dependence of the functions $\cos ^{2}(2(\mathrm{v}))$ and $\sin ^{2}(2(\mathrm{v}))$, and the low er panel the functions (v) and "(v). As a
function of the driving eld am plitudev, these functions show an oscillatory behavior, which can be better appreciated in the low er panels, where the function ( v ) is plotted along side with " ( v ). An interesting feature of this fiunctions is the fact that in general, and to a good approxim ation, there seem sto be a phase shiff of $=2$ betw een " (v) and (v), which corresponds to a distance of $v \quad 0: 4$ betw een their $m$ axim a. This $m$ eans that to (alm ost) every maxim a of
(v) corresponds a zero of" (v) (the D L points) and vice versa, w th the only exceptions occurring at the rst maxim a or the rst zero of this functions. N otice also that (v) does not oscillate sym $m$ etrically around zero, w th the clear consequence that the peaks in the functions $\cos ^{2}(2(\mathrm{v}))$ and $\sin ^{2}(2(\mathrm{v}))$ have uneven heights, w ith altemating high and low peaks, although w ith an overalldecrease in height. T his altemating pattem ofm axim a seem $s$ to be a general feature of the system, which we have found for all the values of $t_{0}$ that we exam ined.
$T$ he $D L$ regim $e$, which can be characterized by the param eter $0 \quad t_{0} \mathrm{~m}$ in $(1 ; 1=\bar{v}) \ll 1$, has been studied in several w orks. In this regim e it was found ${ }^{16,22}$ that, at $t=0$, the eigenstates of the system are of the form

$$
\begin{align*}
& j "(0) i=\quad t_{0}-H_{0}(4 v) \dot{\beta} i+\quad \text { pi } \tag{28}
\end{align*}
$$

where $H_{0}(4 \mathrm{v})$ is the Struve function ${ }^{39}$ de ned as

$$
\begin{equation*}
H_{0}(4 v) \quad{\underset{n}{n}}^{\mathrm{X}} \frac{\mathrm{~J}_{2 n+1}(4 \mathrm{v})}{2 \mathrm{n}+1} \tag{29}
\end{equation*}
$$

In $F$ igs. $7,8,9$, in the low er panelwe have plotted w ith a dash-dot line the fiunction $!_{0}{ }_{4} \mathrm{H}_{0}(4 \mathrm{v})$. A s it w as expected, since in the D L regim e $\sin \ll 1$, then $\sin \quad$, and $(v)!{ }_{4}^{d} H_{0}(4 v)$. The convergence of (v) to the Struve function is clearly slow er for the bigger values of $t_{0}$. It is how ever rather rem arkable that the Struve function seem $s$ to approxim ate well the function (v) much before the D L regim e condition is satis ed ( 1 ); for exam ple, for $t_{0}=0: 5$, and $v=1$, or $t_{0}=1$ and $v=4$, which both give $=0: 5<1$ we already see a good agreem ent betw een those tw o functions. O ne can also see from Fig. $7,8,9$ that the Struve function correctly gives the height of the $m$ axim a in ( v ), w th the di erence betw een those two functions being $m$ ostly a phase di erence that tends to zero as $v!1$. From the asym ptotic form of the Struve function in the lim it v! 1 we obtain that, in that lim it,

$$
\begin{equation*}
\text { (v) } \quad \frac{r}{0} \frac{1}{2} \operatorname{vin}(4 v \quad=4) \quad \sin (4 v \quad=4) \quad \text { for } v!1 \text { : } \tag{30}
\end{equation*}
$$

where we de ned $\mathrm{P} \overline{=32}{ }^{0}=\mathrm{P} \overline{=32} \frac{1}{\mathrm{~F}} \mathrm{v}_{\mathrm{v}}$, for $\mathrm{v}>1$. W e will call the "D L param eter". Eq. 30) establishes a nige connection betw een the D L param eter and the am plitude of the oscillations in the function (v).
D. T im e-evolution operator

To nd out the tim e evolution of an initial state of the form jai or bi, we can use the eigenstates at time $t=0$, as given by Eq.(27). From that equation we can express ji and bi in the form

$$
\begin{align*}
& \dot{j} i=\cos j "(0) i \quad \sin j^{\prime \prime}(0) i ; \\
& \mathrm{b} \mathrm{i}=\sin j{ }^{\prime \prime}(0) i+\cos j^{"(0) i}: \tag{31}
\end{align*}
$$

From these, it is now straight forw ard to construct tw o orthogonalsolutions to Schrodinger's equation which, at $t=0$, correspond to each one of the eigenstates of $\mathrm{H}_{0}$ :

$$
\dot{\beta}(t) i=e^{i " t} \cos \quad j \quad "(t) i \quad e^{i " t} \sin \quad j^{"}(t) i
$$

and

$$
\begin{equation*}
\text { bo (t) i= } e^{\mathrm{i} " t} \sin \quad j \quad "(t) i+e^{i " t} \cos \quad j^{"(t) i ; ~} \tag{32}
\end{equation*}
$$

where $\dot{\beta}(0) i=\dot{\beta} i$ and $\underset{f}{ }(0) i=$ bi. $U$ sing Eq.(24) into above expressions we get

$$
\dot{a}(t) i=\left[\cos K(t) e^{i " t}+\sin Z(t) e^{i " t}\right] j \dot{\beta} i+\left[\cos Z(t) e^{i " t} \quad \sin \quad K(t) e^{i " t}\right] b \operatorname{bi}
$$

and

The tim e-evolution operator for this system, which is de ned by the equation $j(t) i=U(t ; 0) k(0) i$, can be extracted, in the basis fai; pig, directly from the expressions above

$$
\mathrm{U}_{\mathrm{ab}}(\mathrm{t} ; 0)=\begin{array}{lr}
u_{\mathrm{aa}}(t) & u_{\mathrm{ba}}(t)  \tag{34}\\
u_{\mathrm{ba}}(t) & u_{\mathrm{aa}}(t)
\end{array} ;
$$

where,

$$
\begin{align*}
& u_{a a}(t)=\cos K(t) e^{\mathrm{i}^{\prime \prime t}}+\sin \quad Z(t) e^{i " t} ; \\
& u_{b a}(t)=\cos Z(t) e^{i " t} \quad \sin K \quad(t) e^{i " t}: \tag{35}
\end{align*}
$$

The subindex $a b$ in $U_{a b}$ is there to rem ind us of the basis used to represent the tim e-evolution operator.
A nother w ay to arrive at the sam e result is by $m$ aking use of the generalexpression $\mathbb{E} q$.(27) in $M$ ilfeld and $W$ yatt ${ }^{40}$ ]

$$
\begin{equation*}
U(t ; 0)=(t) e^{i t \quad{ }^{1}(0)} \tag{36}
\end{equation*}
$$

where the colum ns of the F loquet m atrix $\quad(\mathrm{t})$ are the com ponents of the FES of the system, and is a diagonal $m$ atrix whose com ponents are the quasi-energies of the system. For our system, from Eq. (24), the F loquet $m$ atrix is

$$
(t)=\begin{array}{cccc}
K & (t) & Z & (t)  \tag{37}\\
Z & (t) & K & (t)
\end{array} ;
$$

and $=" z_{z}$.

## IV . DYNAM IC LOCALIZATION

It is of particular interest to study the situation where the the system 's initial state is a supenposition of the eigenstates of $\mathrm{H}_{0}$. In particular, specially in the context of quantum wells, a particularly interesting initial state is one in which the electron is localized in one of the wells. Such an initial state corresponds to $j(0) i=j l i \quad \frac{1}{\overline{2}}$ (jai+ bii), or $j(0) i=2 i \quad \frac{1}{\overline{2}}$ ( j ji jbi ). In this case, we are interested in calculating the probability to nd the system at that sam e location after a tim $e t$. The solution can be found by applying the transform ation $V=p^{1} \frac{1}{2}(z+x)$, which corresponds to the change of basis fai; big ! fji; Rig, to the evolution $m$ atrix in Eq.(34). The resulting $m$ atrix, $\mathrm{U}_{12}=\mathrm{V} \mathrm{U}_{\mathrm{ab}} \mathrm{V}^{1}$, can be written as

$$
\mathrm{U}_{12}(\mathrm{t} ; 0)=\begin{array}{ll}
\mathrm{u}_{11}(\mathrm{t}) & \mathrm{u}_{21}(\mathrm{t})  \tag{38}\\
\mathrm{u}_{21}(\mathrm{t}) & \mathrm{u}_{11}(\mathrm{t})
\end{array} ;
$$

w ith

$$
\begin{align*}
& u_{11}=\operatorname{Re}\left(u_{\mathrm{aa}}\right)+\operatorname{iIm}\left(u_{\mathrm{ba}}\right) ; \\
& u_{21}=\operatorname{Re}\left(u_{\mathrm{ba}}\right) \quad \operatorname{iIm}\left(u_{\mathrm{aa}}\right): \tag{39}
\end{align*}
$$

It is a well-known fact that dynam ic localization occurs only at the points where the quasi-energies vanish, i.e. $"(v)=0$. At th is particular values ofdriving eld am plitude $v$, as it can be seen from Eqs. (34) and 35), the dynam ics of the system becom es strictly periodic, w ith period $2=$ !, for any initial condition. The points where $\sin (v)=0$ also produce a periodic evolution of the system (except for an overall tim e-dependent phase factor), but only for the particular initialconditions j (0)i= jai or j (0)i= bi.
 function of tim e), that the system, if localized in a well (e.g. jli ) at tim $e t=0$, would rem ain in that well at a later timet. For " $(v)=0$, and from Eqs. 35,39) we get

$$
\begin{equation*}
\left.\left.u_{1 ; 1}(t)=\cos \mathbb{R} e(K(t))+i \operatorname{Im}(Z(t))\right]+\sin \mathbb{R} e(Z(t))+i \ln (K(t))\right] ; \quad \text { at } D L \text { points: } \tag{40}
\end{equation*}
$$

Since this probability is periodic, $\mathrm{u}_{1 ; 1}(0)=\mathrm{u}_{1 ; 1}(2=!)=1$, it is interesting to see what is the value of this function half-w ay through a cycle of the eld, that is, for $!t=$. From Eq. 60) we can deduce that $K(=!)=K(0)=\cos$, and $Z(=!)=Z(0)=\sin . U$ sing this, we get from the above equation

$$
\begin{equation*}
u_{1 ; 1}(=!)=\cos ^{2} \quad \sin ^{2}=\cos (2) ; \quad \text { at } D L \text { points: } \tag{41}
\end{equation*}
$$

W ewill show in the follow ing gures that the function cos(2 ) plays an important role in quantifying how good is the localization of the system at the D L points.

In the low er panels of $F$ igs. $7,8,9$, we have placed dots on the quasi-energy functions " (v), at di erent values of $v$. In the upper panel in $F$ igs. $10,11,12$ we show, for each one of those points, the corresponding probability $\left.j_{1 ; 1}(t)\right\}$, as given by Eqs. (35), (39) . T his probability gives the location of the particle, as a function of tim e, when starting from the in itial state jli. In $F$ ig. 10 we study the case $t_{0}=0: 5$. In this plot one can see that the probability evolves in a $m$ anner that is typical of the high frequency regim e which has been am ply studied in the literature. The function can be described as of the form cos (" $t$ ) + sm alltim e-periodic oscillations. C learly, at the $D L$ points ( $A, B, C, D$ ), when " = 0 , the probability is exactly periodic (period 2 !) and oscillates betw een 1 and a value that depends on the driving eld am plitude $v$ and on $!_{0}$. A s derived before, in the $m$ iddle of the driving period, the probability $j_{1 ; 1}{ }^{?}=\cos ^{2}(2$ (v)).
$G$ iven the correspondence betw een the $m$ axim a of $(v)$ and the zeros of " ( $v$ ), we can conclude that the $m$ in im a of the function $\cos ^{2}(2(\mathrm{v}))$ tells us the value of the probability $j_{1 ; 1}(\mathrm{t})$ 予 halfway through the driving eld period ( $t=(=!)$,
 gives us in form ation about the extend to which the particle is localized when the D L points are reached. A swe can see in the low er panels of $F$ igs. $10,11,12$, when the function $j \mu_{1 ; 1}(t) ?$ has a localm inim um at $t==$, then $\cos ^{2}(2(v))$ is close to be the absolute $m$ inim um value that $j \mu_{1 ; 1}(t) f$ reaches through out a whole period, $P_{1}=m$ in ( $\left.j \mu_{1 ; 1}(t) f\right)$. It is therefore an im portant num ber for describing the am ount of localization that can be achieved in the system. $W$ hen the function $j_{1 ; 1}(t) f$ has a localm axim um at $t=\quad=!$, then $\cos ^{2}(2(v))$ is still equal to that value but this is not necessarily close to $P_{1}$ (specially when we are far from the $D L$ regim e). This is the case at points $B$ and $D$ in those gures. Surprisingly, how ever, $\mathrm{P}_{1}$, for cases B and D, is given, to a certain approxim ation, by the value of the function $\cos ^{2}(2(v))$ at the $m$ inim a that corresponds to the next DL point. W e do not know why this should be so but it was found to be the case in all the cases that we exam ined. A ccording to this, the D L points can be grouped in pairs, w ith ( $B, C$ ) having a sim ilar am ount of localization, given by $\cos ^{2}\left(2\left(v_{c}\right)\right)$; points ( $\left.D, E\right)$ w ith a localization given by $\cos ^{2}\left(2\left(v_{E}\right)\right)$, and so on. It is therefore the deeper $m$ in im a in $\cos ^{2}(2(v))$ that give us directly the am ount of localization in the system .

A $n$ interesting question to ask, because of practical applications, is whether there is a sim ple relationship betw een the am ount of localization $P_{1}, t_{0}$ and $v$. In other words, given a particular am ount of localization $P_{1}$, and a given $t_{0}$, what is the required driving eld am plitude for the system to achieve such level of localization? To answ er this question in the $D L$ regim e (w ere we expect a high level of localization, $\mathrm{P}_{1}<1$ ), one can use Eq. (30) to derive an approxim ate relationship between $P_{1},!_{0}$ and $v$. At the $m$ axim a of (v) (Dlpoints), (v) , which gives $P_{1}=\cos (2) \quad 1 \quad 4^{2}=1 \quad \overline{8} \frac{\dot{\varphi}_{0}^{2}}{v}$, from which one nally gets

$$
\begin{equation*}
\mathrm{v} \quad \frac{\dagger_{0}^{2}}{8\left(1 \quad P_{1}\right)}: \tag{42}
\end{equation*}
$$

This sim ple equation, which has been derived assum ing $v>1$; $\ll 1$, already gives good results even for a localization as low as $P_{1}=0: 5$, w ith the accuracy im proving further for higher values of $P_{1}$. For $P_{1}=0: 5$ the result is v $0: 78!_{0}^{2}$, for $P_{1}=0: 9$ one obtains $v \quad 4!_{0}^{2}$ and for $P_{1}=0: 99$ it gíves $\mathrm{v} 40!_{0}^{2}$.

## V. H IG H-ORDER HARMONIC GENERATION

The expected value of the dipole $m$ om ent of the system can be calculated from the expression

$$
\begin{equation*}
\text { hd (t) } i=h(t) j j(t) i=h(0) j \quad x(t) j(0) i ; \tag{43}
\end{equation*}
$$

where

$$
\begin{equation*}
x \text { ( } t \text { ) } \quad U_{a b}(t)^{Y} \quad x U_{a b}(t) \text {; } \tag{44}
\end{equation*}
$$

and using Eqs.(34), we get

For a generalinitial condition of the form $j(0) i=c_{a}$ jai+ $\mathrm{b}_{\mathrm{g}}$ gi we get

If we now de ne the follow ing tim e-periodic functions,
R ( t )
$\operatorname{Re}(\mathrm{K}$
( t$)$ ) $\operatorname{Re}(\mathrm{Z}(\mathrm{t}))+\operatorname{Im}(\mathbb{K}$
( t$)$ ) $\operatorname{Im}(\mathrm{Z}(\mathrm{t}))$
(odd harm onics),
Q ( t$) \quad \operatorname{Re}(\mathbb{K}$
( t$)$ ) $\operatorname{Im}(\mathrm{K}(\mathrm{t}))$
$\operatorname{Re}(Z$
( t$)$ ) $\operatorname{Im}(\mathrm{Z}(\mathrm{t}))$
(even harm onics),
$P(t) \quad \operatorname{Im}(K(t))^{2}+\operatorname{Re}(Z(t))^{2}$ (even ham onics),
then, using this, and plugging Eqs. (35) into Eq. (46), we obtain (after som e lengthy algebra) the nal expression

$$
\begin{align*}
& +[\cos (2) \cos (2 t)+2 \sin (2) R(t) \quad 2 \cos (2) \sin (2 t) Q(t) \quad 2 \cos (2) \cos (2 t) P(t)] R e\left(2_{0}\right)  \tag{48}\\
& +[\sin (2 t) \quad 2 \cos (2 t) Q(t)+2 \sin (2 t) P(t)] \operatorname{Im}\left(2 \mathbf{c}_{0}\right):
\end{align*}
$$

The quantities , ", P ( $t$ ); $\mathrm{Q}(\mathrm{t})$; $\mathrm{R}(\mathrm{t})$ depend on v , even though, we do not explicitly indicate so in this notation. W e will refer to the initial condition where $\dot{j}_{a} j=1$ or $\dot{j}_{j} j=1$ (and therefore $c_{a} G_{b}=0$ ), as the "Optical" Initial
 Tunneling" InitialC ondition (CTIN).

From the expectation value of the dipole $m$ om ent, one can obtain the (coherent) em issions spectrum of the system from the expression $j() j^{2}=\frac{1}{T}{ }_{t_{t_{0}}+T} d t e^{i t} h d(t) i^{2}$.

Eq.(48) deserves $m$ any com $m$ ents. $N$ otice that generally, there is low-frequency generation, with frequency 2 " for all initial conditions. O nly at som e particular driving am plitudes this can be prevented. For O IC the low-frequency com ponent can be suppressed only when $\sin (2)=0$; for $T I C$ only when $\cos (2)=0$. There is alw ays low -frequency generation at any driving am plitude for C T IC. There is odd-harm onics generation, at frequencies (2n 1)! and due to the term $s w$ th $R(t)$. This ham on ics are generated except when cos (2) = 0 for 0 IC and except when $\sin (2)=0$ for T IC. Interestingly enough, C T IN can not generate odd harm onics. Even harm onics, at frequencies 2 n ! 2 " occur because of the presence of term $s(\sin (2 t)$ or $\cos (2 t)) Q(t)$ and $(\sin (2 t)$ or $\cos (2 t)) P(t)$, and are generated except when $\sin 2(\mathrm{v})=0$ for O IC and except when cos2 $(\mathrm{v})=0$ for TIC. They are always present for C T IC.

For a general driven H am iltonian that possesses the D ynam ical Sym m etry (D S) H $(x ; t)=H(x ; t+\quad=2)$ it has been proven ${ }^{41}$ that the HHG from a F loquet eigenstate consists of only odd harm onics. O ur Ham iltonian, Eq. (14), is certainly of this kind since the quantum operator that corresponds to $x$ is $x$, and therefore, if $x!x$, and $t!t+=2$, the $H$ am iltonian in Eq. (14) rem ains the sam e. A ccording to this, a good check for our result can be done by replacing in Eq. (48) the initial condition $C_{a}=\infty, G_{0}=\sin$ which corresponds to the in itial state being already a F loquet eigenstate [see Eq. (27) ]. A fter doing that, one obtains hd $(t) i==2 R(t)$, which $m$ eans that this state only generates odd-harm onics, in agreem ent with the dynam icalsym $m$ etry argum ents developed in the citation above.

A s our result (48) show $S$, in a tw o-level system it is possible to generate both even and odd harm onics. This has also been found in num ericalcalculations for a double quantum well${ }^{42}$. The kind of ham onics present in the spectrum is dependent on the initial condition, the driving am plitude and also the phase of the driving eld. In this work we have chosen a driving force of the form cos(! t); how ever, in the $m$ ost general case of tim e dependence of the form $\cos (!t+$ ), the driving phase , in general, plays an im portant role in determ ining the harm onic content of the spectrum. For the case $\sin (!t)$ see $G$ authey et $a^{366}$.

It has been argued ${ }^{41}$ that in system $s$ that get ionized during the course of the interaction w ith the eld, only one resonant F loquet state (the one w th the longest life-tim e) contributes to the harm onic spectrum and therefore this could explain the absence of even-harm onic generation in $m$ ost experim ents. There are several experim ental results that involve lasers interacting with solid targets, in which even ham onics and odd harm onics are generated. Even though ionization takesplace, the presence ofeven harm on ics hasbeen attributed to the lack ofD $S$ in the $H$ am iltonian. For system $s w$ here the $m$ ain source of harm onic radiation are bound-bound transitions, it is not clear how to justify the use of only one of the FES in the calculation of the HG of the system. In those kinds of system we w ill argue in future work that, if the evolution of the system is adiabatic under the e ect of a laser pulse, then again, only odd-harm onics are generated. For non-adiabatic evolution, we expect to see generation of even and odd harm onics and also dependence on the initial phase of the driving. It is interesting to check our results for the tim e dependent dipole $m$ om ent of the system in the $D L$ regim $e$. A s we showed before, in the lim it of perfect $D L$, where $v!1$ or $t_{0}!0$, one gets $=0, K(t)$ becom es pure real, $Z(t)$ becom es pure im aginary, and therefore $R(t)=Q(t)=P(t)=0$. $T$ he result for the dipole $m$ om ent is therefore
$w$ ith being the phase di erence betw een $C_{a}$ and $\Phi_{b}$. This is the zeroth-order expression in the rst-order perturbative results obtained by Delgado and G om ez-Llorente ${ }^{23}$. C learly, in this lim it there is no HG.From this it is clear that in the case of a driven tw o-level system, D L and H H G are at odds; the greater the localization, the sm aller the HHG . $T$ he am plitude of any harm onic com ponent of the em ission spectrum of the system (except the low frequency one), as a function of increasing driving eld strength $v$ should in itially increase, then plateau (w th oscillations) and nally decrease as $v$ is further increased.
$N$ ear the D L regim e we can obtain spm e expressions and com pare them with the perturbative results obtained in other works ${ }^{16,21,23}$. For $v>1$ and $=\frac{0}{32} \frac{0}{v}$, we found that the behavior of the functions $K(t)$ and $Z(t)$ is

$$
\begin{array}{cc}
K(t) & \operatorname{Re}(K(t))+i \\
Z(t) & (t)+i \operatorname{Im}(Z(t)): \tag{50}
\end{array}
$$

Here ( $t$ ) and ( $t$ ) are periodic functions (even and odd respectively) w ith am plitude close to one. A s we have show $n$ before, in this regim $e$, the am plitude of the oscillations in the function ( $v$ ) is also proportional to. . A ccording to this, and using Eq. (47), we see that in this regim $e, R(t) /, Q(t) /, P(t) /{ }^{2} . W$ e now rew rite Eq. (48) in a form that $m$ akes evident the $m$ agnitude of the di erent term $s$ that contribute to the dipole $m$ om ent,

$$
\begin{align*}
& \text { h } \\
& \sim^{\sim} \cos (2 t)+R^{\prime}(t)+2^{2 \sim} \sin (2 t) \sim(t)+2^{3 \sim} \cos (2 t) \\
& +\cos (2 t) \quad 2 \sin \left(2 t \mathbb{L}(t)+4^{2} \sim^{\prime}(t) \quad 2^{2} \cos (2 t) \mathbb{P}^{\prime}(t) R e\left(2 c_{a} c_{b}\right)\right.  \tag{51}\\
& \text { h } \\
& +\quad \sin (2 t) \quad 2 \cos \left(2 \emptyset(t)+2^{2} \sin (2 t) \mathbb{P}^{\sim}(t) \operatorname{Im}\left(2 G_{a} G_{b}\right):\right.
\end{align*}
$$

where $R^{\sim}(t)=R(t)=, ~ Q(t)=Q(t)=, P^{\sim}(t)=P(t)={ }^{2}$, and $\sim=\quad=\quad \sin (4 v \quad=4)$. From this expression we can see that in the D L regim e, O IC generates low frequency and odd-harm onic radiation to second order in and even ham onic generation is forth order in this param eter. For T IC there is strong low frequency generation independent of any of the param eters of the system (provided we are in D L regim e); even harm onic generation is second order and odd harm onic generation is forth order in. For CTIC the situation is sim ilar to T IC except that no odd-harm onic radiation is generated at all.

As $m$ entioned before, from the general expression for the dipole $m o m e n t$, since " = " (v) and $=$ (v), with successive points where either (v) or " (v) vanish, there is a lot of variation in the com position (in term s of odd or even harm onics) of the spectrum of this system as a function of the am plitude of the driving eld. The interesting exception being the CTIC where even ham onics are alw ays generated and odd ham onics are never generated.

In Fig.13, 14 and 15 we show the em ission spectrum for three distinct initial conditions ( O IC , T IC ,C T IC) and for two values of the driving eld amplitude. W hat is com $m$ on to all this plots is the typical pro le of harm onic generation that has been found theoretically and experim entally in di erent system s. It consists of a plateau where the am plitudes are of sim ilar m agnitude (uctuations are of one to tw o orders ofm agnitude typically), follow ed by a frequency cut-o after which the harm onic am plitudes decay very quickly (exponentially in n!).

From the structure of the FES, like the one shown in Fig. 6, one can see that there is a cut-o in the harm onic com ponents of the eigenstates, which occurs at $N_{e}=2 \mathrm{v} \quad 1$ (for v 11 ). The location of the cut-o in the em ission spectrum of the system follow s from the location of the cut-o in the eigenstates, since the functions $R$ ( $t$ ); $Q$ ( $t$ ); $P$ ( $(t)$ are second order in the FES com ponents. $R(t) ; Q(t) ; P(t)$ therefore have cut-o $s$ at $N$ cut $=2 N_{e}=4 v \quad 2 . T$ his is the sam e cut-o that we expect to see in the em ission spectrum of the system.

A s we can see in F ig. 13, 14, 15, th is result describes quite well the location of the last peak before the com ponents start to decay exponentially. The linear dependence of $N$ cut on the amplitude of the eld implies that $N$ cut / $\bar{I}$, where $I$ is the intensity of the eld. This result is expected for HHG in system swhere bound-bound transitions are dom inant ${ }^{46,47}$. For dom inant bound-continuum transitions ${ }^{48}, \mathrm{~N}_{\text {cut }} / \mathrm{I}$.

In Fig. 13 we show the em ission spectrum for O IC, and for two di erent values of the driving am plitude. For $v=4: 15$ (which gives 0), we see, from the rst line of Eq \$1) that one expects no low frequency com ponent, odd harm onics and no even ham onics. For v $=4: 5$ (which gives " 0 ), we obtain a strong low frequency com ponent, strong odd-harm onic com ponents and very weak even-harm onics com ponents that are due to the function $P$ ( $t$ ) only (since at " $=0, \sin (2 t)=0$ and therefore $Q(t)$ does not contribute to the spectrum ). $T$ his is a special case since in general, in this regim $e, Q(t)$ 's contribution to $j() j^{2}$ is tw o orders ofm agnitude bigger than the one from $P(t)$.

In Fig. 14 we show the em issions spectrum for $T$ IC for the sam e values of vas before. In the $=0$ case, we can see, from the second line in Eq. (51), that there is a strong low frequency com ponent ( $=2^{\prime \prime}$ ), no odd-harm onics and split even harm onics ( $=2 n \quad 2 ")$. For the case " $=0$ there is a zero frequency com ponent and also odd and even harm onics (not split) of the sam em agnitude.

Finally, in Fig. 15 we show the case when the initial condition is C T IC. From the third line in Eq. (51) we see that, for the case $=0$ we should get a strong low frequency com ponent and split even harm onics. For " $=0$ case there is no static com ponent, only even harm onics (not split).

For the characteristic plateau of $H \mathrm{HG}$ to appear, it was show $\mathrm{n}^{28}$ that $\mathrm{v} \mathrm{p}_{\overline{!_{0}}}$. In this region we have found num erically that $\cos (2)$, which $m$ eans that in the O IC , overall, the odd ham onics are $m$ uch m ore stable $w$ ith respect to changes in the driving am plitude that the even harm onics, which as a whole, do uctuate with v (follow ing the behavior of $\sin (2)$ ). A s one approaches the $D L$ regim e the odd ham onics willdom inate the spectrum for the O IC ( $w$ hich is the in itial condition $m$ ost easily obtained experim entally). It is easy to derive an estim ate for the conditions under which odd-harm onics will dom inate over even harm onics in the O IC. For that we take $0: 1$, so that there is at least one order ofm agnitude di erence in their contributions to Eq.(49). From $=\frac{\overline{3}}{32} \overline{\bar{v}}$ one gets the estim ate

$$
v^{>} 10 t_{0}^{2}:
$$

W hen this condition is satis ed, odd harm onics will clearly dom inate the spectrum in the O IC.
VI. SUMMARYAND CONCLUSIONS

In this work we used a com plete $F$ loquet-G reen operator form alism for the analytical solution of a harm onically driven tw o levelsystem. From this operator w e were able to com pletely solve the system and obtain the quasi-energies and the eigenstates in term s of continued fractions.

W e found that the oscillatory behavior of the quasi-energies of the system can be interpreted as due to multiphoton resonances that occur in an increasingly periodic way as the strength of the driving eld is increased. This multi-photon resonances involve an odd num ber of photons and produce avoided crossings centered at the edges of the energy B rillouin zone " $=0: 5$. The width and am plitude of them increases $w$ th the driving eld am plitude. $T$ he structure of the continued fractions from which the quasi-energies can be obtained $m$ ade it clear that this is the case, since each term in the continued fraction was found to be related to the inclusion of a particular basis state in the calculations, and each avoided crossing studied did only appear when the corresponding term in the continued fraction w as inchuded.
$W$ e were able to obtain analytical expressions for the com ponents of the $F$ loquet eigenstates and from them we constructed the tim e-evolution operator of this system. T he structure of the eigenstates revealed a characteristic pattem, with a "chaotic" region where the com ponents are sensitive to $s m$ all changes in $v$, change sign and have zeros, and a "regular" region where the com ponents depend less sensitively on $v$, and decay exponentially w ith the frequency $n!$. The cut-o frequency that divides the two regions and gives the position of the largest oquet com ponent of the pigenstates is proportional to the driving eld strength $v, N_{e}=2 v \quad 1$, a result that is valid for any $t_{0}\left(\right.$ provided $v>{ }^{\circ} \frac{l_{0}}{!_{0}}$ ).

From the tim e evolution operator we were able to study the D ynam ic Localization phenom ena which is one of the im portant features of this $H$ am iltonian. It is know $n$ that $D L$ is obtained at values of the driving eld strength for $w$ hich the quasi-energies vanish. In $Q$ uantum $C$ om putation, this localization $m$ echanism can be of great im portance for controlling the state of a $q$-bit (as realized for exam ple in a solid state devise such as a double quantum well or a Josephson Junction), since the am ount of tunneling of an electron betw een two adjacent wells can be varied w ith the intensity of the driving eld. In this work we obtained a correlation betw een the D L points and the $m$ axim a of the quantity ( v ) that describes the F loquet eigenstates of the system. A lso, the value of the function cos (2 (v)), at its low est m inim a, was found to give a good approxim ation to the degree of localization of the system at the corresponding D L points. These points appear in pairs $w$ ith sim $m$ ilar degrees of localization corresponding to each pair. W e also found the equation

$$
\mathrm{v} \quad \frac{\grave{t}_{0}^{2}}{8\left(1 \quad \mathrm{P}_{1}\right)}
$$

which, at the D L points, relates the degree of localization $P_{1}$, $w$ th the energy level di erence ! 0 , and the am plitude $v$ of the driving eld (all quantities in units of $h!$ ). This equation can be used to easily estim ate the am ount of localization achievable in this system for a given set of param eters.

For the study of H igh H arm onic G eneration in this system we calculated the expected value of the dipole m om ent which revealed that the em ission spectrum, in general, can contain a low frequency com ponent and odd and even harm onics. The particular com ponents and their am plitudes depend strongly on the initial state of the system and on the speci c driving eld am plitude. W e found that there exists an initial condition (C om plex Tunneling) of the driven two-level system for which no odd-harm onics can be generated at any driving eld strength. For each one of the "pure" initial conditions, nam ely Optical (O IC ), Tunneling (T IC ) or C om plex Tunneling (C T IC ), the driving
am plitudes where the $(v)=0$ produce either pure even harm onic generation or pure odd harm onic generation, depending on the particular initial condition. For all other driving am plitudes there will be in general generation of both kinds of harm onics (except for CT initialcondition). W hen the in itialstate is a F loquet eigenstate, we found that only odd-harm onics are generated, a result that is expected from the D ynam icalSym $m$ etry (D S) of the $H$ am iltonian. In generalwe can say that the em ission spectrum of the driven two-level system is sensitive to di erent param eters, such as the initial preparation, the amplitude of the driving and its phase (phase dependence will be explored in fiuture work).

For sm all values of , but still not deep into the D L regim e ( $0: 15$ ) we showed the di erent $m$ agnitude of the term $s$ that give low frequency, even harm onics and odd harm onics. In the Optical InitialC ondition (O IC) we found that odd harm onic generation is stronger, w ith even harm onics weaker and even nonexistent for particular values of the driving eld am plitude (when (v) $=0$ ). For Tunneling InitialC ondition ( $T$ IC ), even harm onics dom inate, except at the $D L$ points $("=0)$, where even and odd harm onics have approxim ately the sam e am plitude. For $C$ om plex Tunneling Initial C ondition (C T IC) no odd ham onics are generated.

W ell inside the D L regim e, odd harm onics are alm ost exclusively generated in the Optical Initial C ondition, and even harm onics in both of the Tunneling Initial C onditions. In this regim e of high localization, H arm onic generation decreases $w$ ith decreasing, a situation that clearly places both e ects on opposite sides of the param eter space, although w ith signi cant overlap betw een them. In general, for a driven tw o level system, the strongest H H G should occur for higher values of $t_{0}$ and for driving am plitudes $v<10!_{0}^{2}$ (for $>0: 1$ ). For strong $D L$, sm aller values of $t_{0}$ and/or bigger values of $v$ are required, $v>10!_{0}^{2}$ (for $<0: 1$ ). Strong HHG in a two-level system is an em inently non-linear, non-perturbative phenom enon.

The driven tw o-level $m$ odel has been show $n$ to be useful in understanding the basic features of high-harm onic generation experim entally observed in atom $s$ and $m$ olecules, even though obviously the full com plexity of the general processes in atom $s$ and $m$ olecules can not be accounted for $w$ ith this $m$ odel. Them odelpredicts an em ission spectrum $w$ ith a plateau and a cut-o frequency ( $\mathbb{N}$ cut $=4 v \quad 2$ ), whose location depends on the square-root of the intensity of the driving eld (since v/E/P $\bar{I}$ ). Such dependence has been found in system $s$ where bound-bound transitions account for m ost of the HHG $\mathbf{4 6 , 4 9}$. For the case of charge-resonant states of odd-charge m olecular ions it has also been argued ${ }^{21}$ that this simple two-level model can account for the behavior of these $m$ olecules in a strong laser pulse. A square-root dependence of the cut-o frequency w ith the intensity of the laser eld can be found in several experim ents ${ }^{45}$, a fact that is characteristic of a driven tw o-level system and which $m$ ight point in the direction of an e ective tw o-leveldynam ics for som e system $s^{28}$.

HHG and DL are the two mayor features of a driven tw o-level system with a great range of applications in atom ic and solid state system $s$ where coherent sources of radiation and control of quantum states are sought. Through this work we have established a strong connection betw een this tw o phenom ena and provided a detailed description and a deeper understanding of this system.

## A cknow ledgm ents

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A ppendix A: com ponents of the FES

From the de nition of the Floquet-G reen operator, we have shown in Eq. 10 that the residue of the function
 $F$ loquet eigenstate corresponding to the quasi-energy ". If wewrite $j_{p}{ }^{i} K_{p} \dot{j} i+Z_{p}$ bi, then, in principle, from the residue (a m atrix) of $G_{0 ; 0}$ we could determ ine the com ponents $K_{p} ; Z_{p}$. This is only true, how ever, provided the residue does not tum out to be a diagonalm atrix. Unfortunately, this is the case for the system we are considering, since, as wem entioned before, $G_{0 ; 0}(\mathbb{E})$ is a diagonalm atrix ( $\mathrm{V}_{\mathrm{eff}}(\mathrm{E})$ is diagonal) and therefore, its residue only gives us inform ation about $\mathrm{K}_{\mathrm{p}}{ }^{\jmath}$ and $\mathrm{Z}_{\mathrm{p}}{ }^{\jmath}$. From Eq. (8) we can see that the 0 -diagonalcom ponents $\mathrm{G}_{\mathrm{m}}$;0 can give us the needed com ponents:

$$
\begin{equation*}
G_{m ; 0}(E)={ }_{i p}^{X} \frac{1}{E \quad p^{\prime} j_{m}^{\prime \prime} p^{i h} "_{p} j: ~} \tag{52}
\end{equation*}
$$

From this we get that at the pole $E=" \quad$ (and therefore $p=0$ ), the residue $\mathrm{is}_{\mathrm{j}}^{\mathrm{j}} \mathrm{m}$ in " ${ }_{0} \mathrm{j}$. From all these residues for all vahes of $m$, one could therefore extract all the eigenvector com ponents $j \mathrm{~m}$ i.

The $\mathrm{G}_{\mathrm{m}}$;0 operators can be obtained from $\mathrm{G}_{0} ; 0$, as it was shown in $R$ ef ${ }^{26}$. The result is

$$
\begin{align*}
\mathrm{G}_{1 ; 0} & =\mathrm{F}_{0}^{+} \mathrm{G}_{0 ; 0} ; \\
\mathrm{G}_{2 ; 0} & =\mathrm{F}_{1}^{+} \mathrm{G}_{1 ; 0}=\mathrm{F}_{1}^{+} \mathrm{F}_{0}^{+} \mathrm{G}_{0 ; 0} ; \\
\vdots &  \tag{53}\\
\mathrm{G}_{\mathrm{m} ; 0} & =\mathrm{F}_{\mathrm{m}}^{+}{ }_{1} \mathrm{G}_{\mathrm{m}} \quad 1 ; 0={ }_{\mathrm{j}=0}^{\mathrm{n} Y} \mathrm{~F}_{j}^{+} \mathrm{G}_{0 ; 0}(\mathrm{E}) ; \quad \text { form }>0 ;
\end{align*}
$$

and where (show ing explicitly the energy dependence)

$$
F_{j}^{+}(E) \quad\left(V F_{j ; 0}(E)\right)^{1} V=V^{1} V_{e}^{+}(E+j)=\quad \frac{1}{v} v_{a}^{+}(E+j) \begin{gather*}
0  \tag{54}\\
\frac{1}{v} v_{b}^{+}(E+j) \\
0
\end{gather*} ;
$$

and sim ilarly,

$$
\begin{equation*}
G_{m ; 0}(E)=F_{m+1} G_{m+1 ; 0}={\underset{j=0}{n Y} F_{j}^{1} G_{0 ; 0} \quad \text { for } m>0 ; ~}_{\text {i }} \tag{55}
\end{equation*}
$$

w ith

It is not di cult to show using Eqs.(52), (53), and (55), that

$$
j_{m+1}^{\prime \prime} i=F_{m}^{+}(") j_{m}^{\prime \prime} i
$$

and

$$
\begin{equation*}
j_{m}^{\prime \prime} \quad i=F_{m}(") j_{m}^{\prime \prime} i ; \tag{57}
\end{equation*}
$$

w ith " = ".
As we already $m$ entioned, at $E="$ the residue of $G_{0 ; 0}(E)$ is proportional to foi and at $E=\quad$ " the residue is proportional to jai. From this, and using Eq. (57) together with Eqs. (54) and (56), we can write explicitly the two F loquet eigenstates of this system :

$$
\begin{aligned}
& j "(t) i=N \quad\left[:::+\frac{e^{2!!t}}{v^{2}} v_{b}(\quad " \quad 1) y(\quad ") \dot{a i}+\frac{e^{i!t}}{v} v_{a}(\quad ") b i+\dot{\beta} i+\right. \\
& \left.+\frac{e^{i!t}}{v} v_{a}^{+}(\quad ") j b i+\frac{e^{2 i!t}}{v^{2}} v_{b}^{+}(\quad "+1) v_{a}^{t}(\quad ") \dot{\beta i}+:::::\right]
\end{aligned}
$$

and

$$
\begin{align*}
j^{"}(t) i & =N\left[:::+\frac{e^{2 i!t}}{v^{2}} v_{a}(" \quad 1) y_{b}(") \text { bi }+\frac{e^{i!t}}{v} v_{b}(") \dot{j} i+\text { bi }+\right. \\
& \left.+\frac{e^{i!t}}{v} v_{b}^{+}(") j a i+\frac{e^{2 i!t}}{v^{2}} v_{a}^{+}("+1) v_{b}^{+}(") j b i+:::::\right] ; \tag{58}
\end{align*}
$$

w ith N being a norm alization constant. If we use the symmetry relations, $\mathrm{v}_{\mathrm{b}}(\mathrm{E})=\quad$ 寺 ( E$)$ and $\mathrm{v}_{\mathrm{b}}^{+}(\mathrm{E})=\quad \mathrm{y}(\mathbb{E})$ we can w rite this tw o eigenstates in a $m$ ore com pact way,

$$
j \quad "(t) i=k(t) \dot{a} i+Z(t) \text { bi } i
$$

and

$$
\begin{equation*}
j^{"}(t) i=Z(t) \text { jai }+K(t) \text { गbi ; } \tag{59}
\end{equation*}
$$

w ith

$\left.+\frac{e^{2 i!t}}{v^{2}} v_{b}^{+}("+1) v_{a}^{+}(")+\frac{e^{4 i!t}}{v^{4}} v_{b}^{+}("+3) v_{a}^{t}("+2) v_{b}^{+}("+1) v_{a}^{+}(")\right)$
$=N\left[e^{2 \text { in!t }} K_{2 n}\left({ }^{\text {(") }}\right]\right.$;
$\mathrm{n}=1$
 $x^{2}$
$=N\left[\begin{array}{lll}X & \left.e^{i(2 n} 1\right)!t_{2 n} & \left.\left.(\quad)^{\prime}\right)\right]\end{array}\right.$
$\mathrm{n}=1$
where $N$ is a norm alization constant so that $k(t) ?+\neq(t) ?=1$, and we have

$$
\begin{align*}
& K_{2 n}(\quad ")=\stackrel{1}{Q}{ }_{n j} \quad \text { for } n=0 \text {; } \tag{61}
\end{align*}
$$

and we used $\operatorname{sg}(x) \quad x=j x$ j.
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${ }^{32}$ For the resonant case, we have obtained a num erical $t$, that can be used for any value of $v$. It was obtained by displacing the rst couple of zeros of the Bessel function $J_{0}(4 \mathrm{v})$ to the left, and linearizing the initial behavior by $\mathrm{m} u$ ltiplying this function by a suitable factor. The resulting expression that approxim ates the behavior of (v) to two decim al points is (v)' $\frac{1}{2}\left(0: 5353+1: 7(\mathrm{v} \quad 0: 5228)^{2}\right) \frac{1+(2 \mathrm{v})^{4}}{1+\left(0: 5353+1: 7(\mathrm{v} 0: 5228)^{2}\right)(2 \mathrm{v})^{4}} \mathrm{~J}_{0}\left(4 \mathrm{v}+\frac{0: 6}{1+5(\mathrm{v} 0: 5228)^{2}} \mathrm{v}\right)$
${ }^{33} \mathrm{C}$ learly, in the lim itn! $1, \mathrm{~F}_{\mathrm{n}}(E)!\mathrm{F} \quad$ (E). Even though the convergence of continued fractions is a com plex $m$ athem atical sub ject, we have not yet found a continued fraction related to a physical system which failed to have a lim it. For all calculations that involve a C F. in th is paper, convergence to any speci ed precision was alw ays ach ieved.
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F IG . 1: Q uasi-energy as a function of driving amplitude (v), for di erent values of $\downarrow_{0} \quad!_{0}=!\quad 1$ (high frequencies) .


F IG . 2: Q uasi-energy as a function of driving amplitude, for di erent values of $\downarrow_{0} 1$ (low frequencies). The functions $0: 05 \mathrm{~J}_{0}(4 \mathrm{v})$ are plotted w ith dotted lines for com parison.


F IG . 3: Solutions of Eq. (20) as a function of driving amplitude for the resonant case ( $._{0}=1$ ). The avoided crossings structure can be accounted for, in an approxim ate way, by a set of crossings of the eigenvalues corresponding to the rst-order FES indicated on the left of the gure. A voided crossings A and $C$ are $m$ ainly due to a 3 photon resonance between the corresponding FES; B corresponds to a 5 photon process.


FIG. 4: Solutions of truncated versions of Eq. (22) : $F_{n}^{+} F_{n}=v^{2}$, for di erent values of $n$. In $a$ ) $n=0$; b) $n=1$; $c$ ) $n=2$; $d$ ) $n=3$. $T$ he labelsb $2 n$ and a $2 m \quad 1$ correspond to term $s$ in the CFsin Eq. (23) of the form $+2 n$ and $+2 m+1+$ fo $A s m$ ore term s are inchuded new avoided crossings appear. T he signs are used to indicate each one of the tw o solutions that originate at the points $=2 n$ in the $y$-axis.


F IG . 5: C om ponents of the FES for $\mathfrak{t}_{0}=3$ and for two di rent values of the driving am plitude (v $=1: 2$; $1: 6$ ). The avoided crossing that occurs near $v \quad 1: 4$ is due to a 5 photon process between two rst-order FES.


FIG. 6: C om ponents of the FES for $t_{0}=1$ and for eight di erent values of the driving am plitude. The logarilm ic plots show the "plateau" structure of the FES, which gives rise to the well-known plateau studied in HHG. The cut-o location ( N e) follow s the approxim ate rule $\mathrm{N}_{\mathrm{e}}=2 \mathrm{v} \quad 1$.

 $j \quad "(0) i=\cos (v) j a i+\sin (v)$ joi. The lower panel shows the functions (v) (solid line) and " (v) (dash line). The dash-dot line corresponds to the Struve function ${\underset{0}{0}}^{-}{ }_{4} H_{0}(4 v)$. P oints A, B , C , D , correspond to the values of v for which D L occurs.



FIG. 8: Sam e as in Fig. 7. H ere $\downarrow_{0}=1$.


FIG.9: Same as in Figs. 7,8. H ere $t_{0}=2$.


FIG. 10: The probability to rem ain in the in itial state jli as a function of time $(=!t)$, for 9 di erent values of the driving am plitude and for $t_{0}=0: 5$. The lower panels show that the function $\cos ^{2}(2(\mathrm{v}))$, at the $\mathrm{D} L$ points $(A, B, C, D)$, gives a good approxim ation to the am ount of localization $P_{1}$ in this system. $P_{1}=m$ in $\left(j_{11}(1) j\right)$. In the lower left panel the function $\cos ^{2}\left(2 t_{0}{ }_{4} \mathrm{H}_{0}(4 \mathrm{v})\right)$ is show w th a dash-dot line for com parison.


FIG. 12: As in F igs. 10,11 . H ere $t_{0}=2$.


F IG . 13: The em ission spectrum of the system, for the "O ptical" Initial Condition (O IC ) and for two values of the driving am plitude: $v=4: 5$ corresponds to a D L point and $v=4: 15$ gives $(4: 15)=0$. The Fourier com ponents of hd ( $t$ )i are connected $w$ ith a continuous line for better visualization.


F IG. 14: Sam e as in F ig. 13. H ere for "Tunneling" in itial condition (T IC ).


FIG. 15: Sam e as in Fig. 13,14. H ere for "C om plex Tunneling" Initial C ondition (C T IC ).

